

DESCRIPTION

The ISLT100xV series optocouplers consists of an infrared emitting diode optically coupled to an NPN silicon photo transistor.

These devices belong to Isocom Long Creepage Range of Optocouplers.

FEATURES

- Long Creepage 8mm
- High AC Isolation voltage 5000V_{RMS}
- CTR Selections Available
- Wide Operating Temperature Range -55°C to 110°C
- Pb Free and RoHS Compliant
- UL Approval E91231
 VDE Approval 40042752

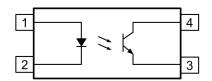
APPLICATIONS

- Switching Mode Power Supply
- System Appliances
- Measuring Instruments
- Telecommunication Equipments
- Signal Transmission between Systems of Different Potentials and Impedances

ORDER INFORMATION

 Available in Tape and Reel with 3000pcs per reel





- Anode
- 2 Cathode
- 3 Emitter
- 4 Collector

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C)

Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

Input

Forward Current	60mA
Peak Forward Current (1µs, pulse)	1.5A
Reverse Voltage	6V
Power dissipation	100mW

Output

Collector to Emitter Voltage V _{CEO}	80V
Emitter to Collector Voltage V_{ECO}	7V
Collector Current	50mA
Power Dissipation	150mW

Total Package

Isolation Voltage	$5000V_{\text{RMS}}$
Total Power Dissipation	250mW
Operating Temperature	-55 to 110 °C
Storage Temperature	-55 to 125 °C
Lead Soldering Temperature	260°C
(10s)	

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

INPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward Voltage	V_{F}	$I_F = 50 \text{mA}$		1.45	1.5	V
Reverse Current	I_R	$V_R = 6V$			10	μΑ
Input Capacitance	C_{IN}	$V_F = 0V$, $f = 1kHz$		50		pF

OUTPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector-Emitter Breakdown Voltage	$\mathrm{BV}_{\mathrm{CEO}}$	$I_{C} = 0.1 \text{mA}, I_{F} = 0 \text{ mA}$	80			V
Emitter-Collector Breakdown Voltage	$\mathrm{BV}_{\mathrm{ECO}}$	$I_E = 0.1 \text{mA}, I_F = 0 \text{mA}$	7			V
Collector-Emitter Dark Current	I_{CEO}	$V_{CE}=20V,I_F=0mA$			100	nA



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

COUPLED

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Current Transfer Ratio	CTR	$I_F = 5 \text{mA}, V_{CE} = 5 \text{V}$				%
		ISLT1001V	50		600	
		ISLT1007V	80		160	
		ISLT1008V	130		260	
		ISLT1009V	200		400	
		$I_F = 10 \text{mA}, V_{CE} = 5 \text{V}$				
		ISLT1002V	63		125	
		ISLT1003V	100		200	
		ISLT1004V	160		320	
		$I_F = 1 \text{mA}, V_{CE} = 5 \text{V}$				
		ISLT1002V	22			
		ISLT1003V	34			
		ISLT1004V	56			
Collector-Emitter Saturation Voltage	V _{CE(sat)}	$I_F = 10 \text{mA}, I_C = 1 \text{mA}$			0.3	V
Floating Capacitance	C_{f}	$V_F = 0V, f = 1MHz$			1.0	pF
Turn On Time	t _{on}	$V_{CE} = 2V$, $Ic = 5mA$, $R_{L} = 100\Omega$		4		μs
Turn Off Time	$t_{ m off}$	KL — 10022		3		μs
Output Rise Time	$t_{\rm r}$				18	μs
Output Fall Time	t_{f}				18	μs

ISOLATION

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Isolation Voltage	$V_{\rm ISO}$	R.H. = 40% to 60%, t = 1 min (Note 1)	5000			V_{AC}
Input - Output Next after Measist and cwith in	R _{I-O} out leads sho	R.H. = 40% to 60% orted toget N G ₁ Om 600N/D Cleads short (Note 1)	5x10 ¹⁰ ed together.			Ω



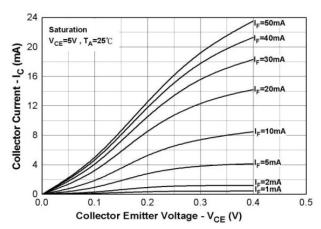


Fig 1 Collector Current vs Collector-Emitter Voltage (1)

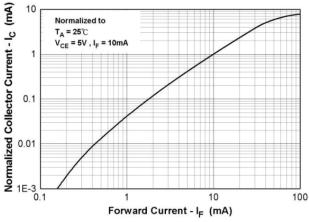


Fig 3 Normalized Collector Current vs Forward Current

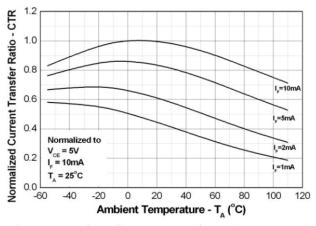


Fig 5 Normalized Current Transfer Ratio vs Ambient Temperature (1)

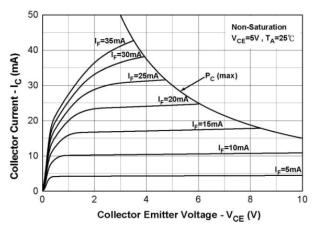


Fig 2 Collector Current vs Collector-Emitter Voltage (2)

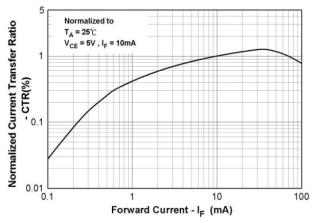


Fig 4 Normalized Current Transfer Ratio vs Forward Current

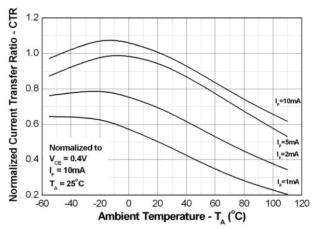


Fig 6 Normalized Current Transfer Ratio vs Ambient Temperature 2)



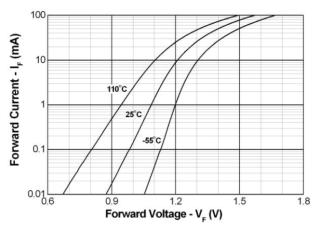


Fig 7 Forward Current vs Forward Voltage

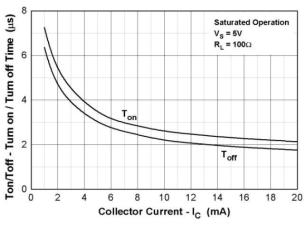


Fig 9 Turn on/off Time vs Collector Current

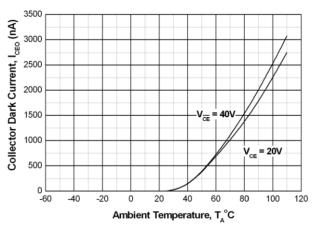


Fig 8 Collector Dark Current vs Ambient Temperature

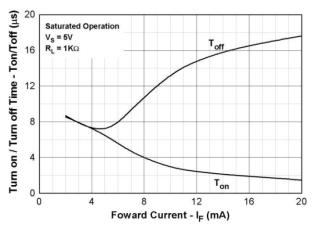
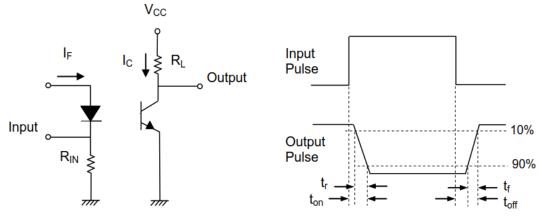


Fig 10 Turn on/off Time vs Forward Current



Switching Time Test Circuit and Waveforms



ORDER INFORMATION

	ISLT100xV			
After PN	PN	Description	Packing quantity	
Any CTR Grade	ISLT1001V, ISLT1002V, ISLT1003V, ISLT1004V, ISLT1007V, ISLT1008V, ISLT1009V	Surface Mount Tape & Reel	3000 pcs per reel	

NB: Units marked ISLT1000V = ISLT1001V

DEVICE MARKING



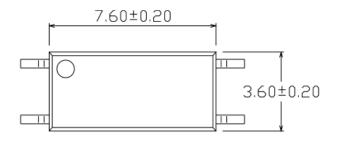
ISLT100_V denotes Device Part Number where "_" denotes the CTR Grade

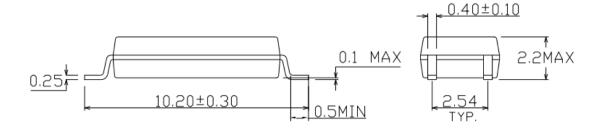
I denotes Isocom

Y denotes 1 digit Year code
WW denotes 2 digit Week code

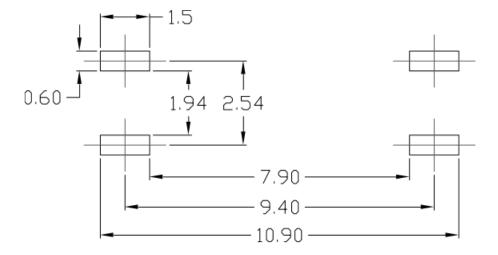


PACKAGE DIMENSIONS (mm)



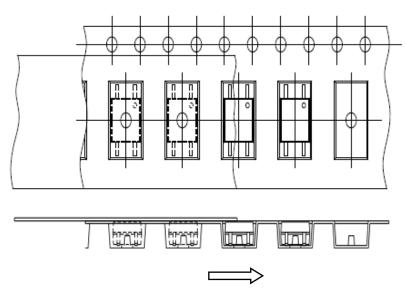


RECOMMENDED SOLDER PAD LAYOUT (mm)

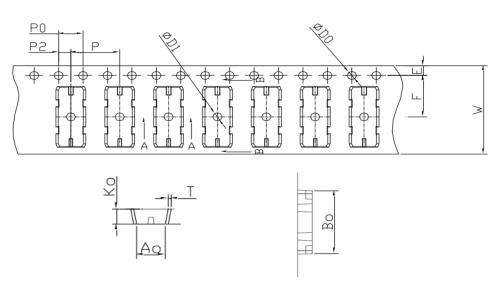




TAPE AND REEL PACKAGING



Direction of feed from reel

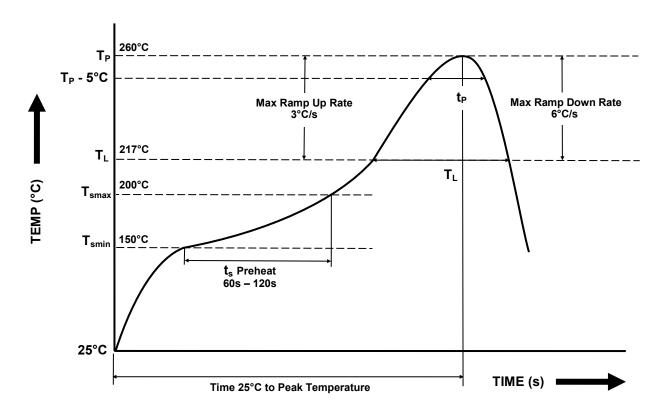


Dimension No.	A ₀	B ₀	D0	D1	E	F
Dimension (mm)	3.9±0.10	10.82±0.10	1.5+0.1/-0	1.5±0.10	1.75±0.10	7.5±0.10
Dimension No.	P0	Р	P2	Т	w	K ₀
Dimension (mm)	4.0±0.15	8.0±0.10	2.0±0.10	0.4±0.05	16.0±0.3	2.25±0.1



IR REFLOW SOLDERING TEMPERATURE PROFILE

One Time Reflow Soldering is Recommended. Do not immerse device body in solder paste.



Profile Details	Conditions
Preheat - Min Temperature (T _{SMIN}) - Max Temperature (T _{SMAX}) - Time T _{SMIN} to T _{SMAX} (t _s)	150°C 200°C 60s - 120s
$\begin{tabular}{lll} \textbf{Soldering Zone} \\ - & \mbox{Peak Temperature } (T_P) \\ - & \mbox{Liquidous Temperature } (T_L) \\ - & \mbox{Time within } 5^{\circ}\mbox{C of Actual Peak Temperature } (T_P - 5^{\circ}\mbox{C}) \\ - & \mbox{Time maintained above } T_L \ (t_L) \\ - & \mbox{Ramp Up Rate } (T_L \ \mbox{to } T_P) \\ - & \mbox{Ramp Down Rate } (T_P \ \mbox{to } T_L) \\ \end{tabular}$	260°C 217°C 30s 60s - 100s 3°C/s max 6°C/s max
Average Ramp Up Rate (T _{smax} to T _P)	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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